

MBR1535CT THRU MBR15100CT

15.0 AMPS. Schottky Barrier Rectifiers



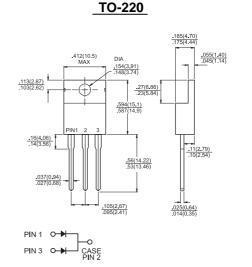
Voltage Range 35 to 100 Volts Current 15.0 Amperes

Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- ♦ Low power loss, high efficiency
- High current capability, low forward voltage drop
- ♦ High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ♦ Guardring for transient protection
- High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- ♦ Cases: JEDEC TO-220 molded plastic body
- Terminals: Leads solderable per MIL-STD-750, Method 2026
- ♦ Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. lbs. max
- Weight: 0.08 ounce, 2.24 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

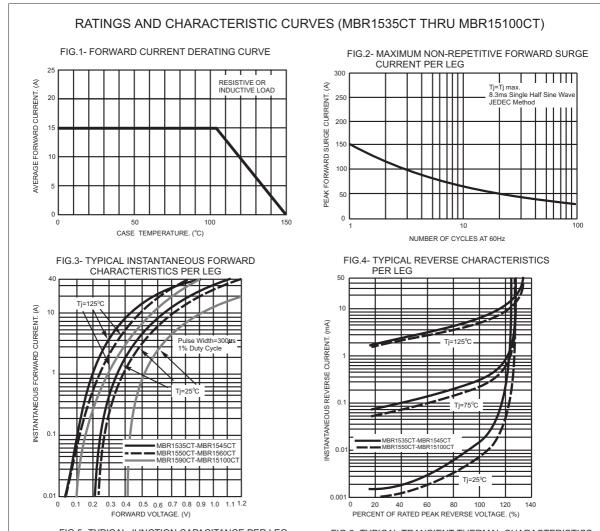
Type Number	Symbol	MBR 1535CT	MBR 1545CT	MBR 1550CT	MBR 1560CT	MBR 1590CT	MBR 15100CT	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	V
Maximum RMS Voltage	V_{RMS}	24	31	35	42	63	70	V
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	V
Maximum Average Forward Rectified Current at T _C =105°C	I _(AV)	15						Α
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20KHz) at Tc=105 $^{\circ}$ C	I _{FRM}	15.0						А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	150					Α	
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	1.0 0.5					Α	
Maximum Instantaneous Forward Voltage at (Note 2) $I_F=7.5A$, $Tc=25^{\circ}C$ $I_F=7.5A$, $Tc=125^{\circ}C$ $I_F=15A$, $Tc=25^{\circ}C$ $I_F=15A$, $Tc=125^{\circ}C$	V _F	0.57 0.84 0.72			0.75 0.65 - -		.92 82 –	V
Maximum Instantaneous Reverse Current @ Tc=25℃ at Rated DC Blocking Voltage (Note 2) @ Tc=125℃	I_R	0.1 15.0		1.0 50.0		0.1 -		mA mA
Voltage Rate of Change (Rated V _R)	dV/dt	1,000					V/uS	
Maximum Thermal Resistance Per Leg (Note 3)	$R \theta JA$ $R \theta JC$	60.0 3.0					€W	
Operating Junction Temperature Range	TJ	-65 to +150					೦	
Storage Temperature Range	Tstg	-65 to +175						ပ္

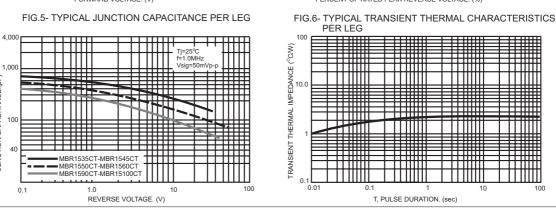
Notes: 1. 2.0us Pulse Width, f=1.0 KHz

- 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
- 3. Thermal Resistance from Junction to Case and Thermal Resistance from Junction to Ambient

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JUNCTION CAPACITANCE (PF)